

DATA SHEET



N-Channel Silicon MOSFET MCH6428 — General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱D		5	A
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	20	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (1200mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	2.8	4.7		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=3A, VGS=4V		38	50	mΩ
	RDS(on)2	ID=1.5A, VGS=2.5V		50	70	mΩ
	R _{DS} (on)3	I _D =0.5A, V _{GS} =1.8V		70	110	mΩ

Marking : ZC

Continued on next page.

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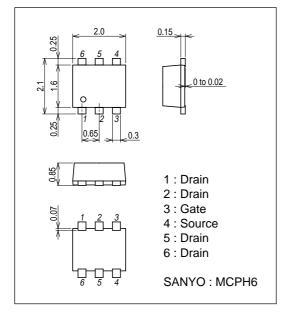
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		340		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		85		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		65		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		10		ns
Rise Time	tr	See specified Test Circuit.		88		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		30		ns
Fall Time	tf	See specified Test Circuit.		61		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =5A		4.4		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=4V, ID=5A		0.92		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =5A		1.35		nC
Diode Forward Voltage	VSD	IS=5A, VGS=0V		0.85	1.2	V

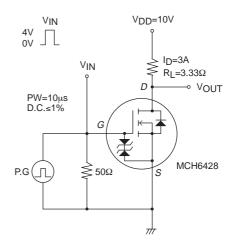
Package Dimensions

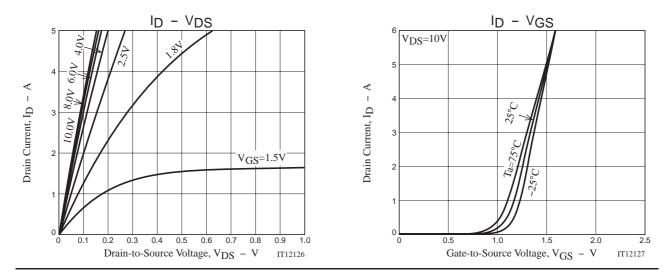
unit : mm (typ)

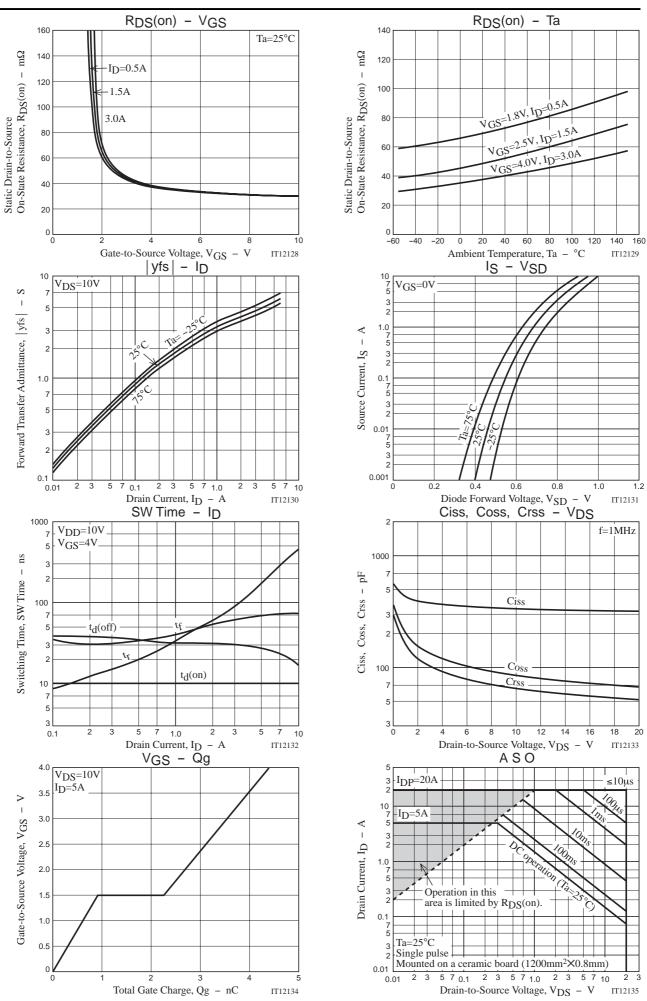
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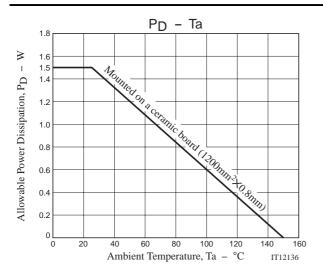
Switching Time Test Circuit







No. A0705-3/4



Note on usage : Since the MCH6428 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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